9-BIT BUS-INTERFACE REGISTER WITH 3-STATE OUTPUTS

SCCS069A - OCTOBER 2001 - REVISED NOVEMBER 2001

- Function, Pinout, and Drive Compatible
 With FCT, F Logic, and AM29823
- Reduced V_{OH} (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- 64-mA Output Sink Current
 32-mA Output Source Current
- High-Speed Parallel Register With Positive-Edge-Triggered D-Type Flip-Flops
- Buffered Common Clock-Enable (EN) and Asynchronous-Clear (CLR) Inputs
- 3-State Outputs

(TOP VIEW) 24 🛮 V_{CC} <u>oe</u> l $D_0 \square 2$ 23 Y_0 $D_1 \square 3$ 22 X1 $D_2 \square 4$ 21 Y₂ $D_3 \square 5$ 20 Y₃ $D_4 \begin{bmatrix} 1 \\ 6 \end{bmatrix}$ 19 Y₄ D₅ [] 7 18 Y₅ $D_6 \square 8$ 17 X Y₆ $D_7 \begin{bmatrix} 1 \\ 9 \end{bmatrix}$ 16 Y₇ 15 🛮 Y₈ D₈ [] 10 14 EN CLR **∏** 11 GND 12 13 CP

P. Q. OR SO PACKAGE

description

This bus-interface register is designed to eliminate the extra packages required to buffer existing registers and provide extra data width for wider address/data paths or buses carrying parity. The CY74FCT823T is a 9-bit-wide buffered register with clock-enable (EN) and clear (CLR) inputs that are ideal for parity bus interfacing in high-performance microprogrammed systems. It is ideal for use as an output port requiring high I_{OL}/I_{OH}.

This device is designed for high-capacitance load drive capability, while providing low-capacitance bus loading at both inputs and outputs. Outputs are designed for low-capacitance bus loading in the high-impedance state.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

TA	PACI	KAGEŤ	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	6	CY74FCT823CTQCT	FCT823C
	SOIC - SO	Tube	6	CY74FCT823CTSOC	FCT823C
	3010 - 30	Tape and reel			FC1023C
-40°C to 85°C	DIP – P	Tube	7.5	CY74FCT823BTPC	CY74FCT823BTPC
-40 C to 65 C	DIP – P	Tube	10	CY74FCT823ATPC	CY74FCT823ATPC
	QSOP - Q	Tape and reel	10	CY74FCT823ATQCT	FCT823A
	SOIC - SO	Tube	10	CY74FCT823ATSOC	FCT823A
	3010 - 30	Tape and reel	10	CY74FCT823ATSOCT	101023A

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

PIN DESCRIPTION

NAME	1/0	DESCRIPTION
D	I	D flip-flop data inputs
CLR	I	When CLR is low and OE is low, Q outputs are low. When CLR is high, data can be entered into the register.
СР	0	Clock pulse for the register. Enters data into the register on the low-to-high clock transition.
Υ	0	Register 3-state outputs
EN	I	Clock enable. When \overline{EN} is low, data on the D input is transferred to the Q output on the low-to-high clock transition. When \overline{EN} is high, the Q outputs do not change state, regardless of the data or clock input transitions.
ŌĒ	Ţ	Output control. When \overline{OE} is high, the Youtputs are in the high-impedance state. When \overline{OE} is low, true register data is present at the Youtputs.

FUNCTION TABLE

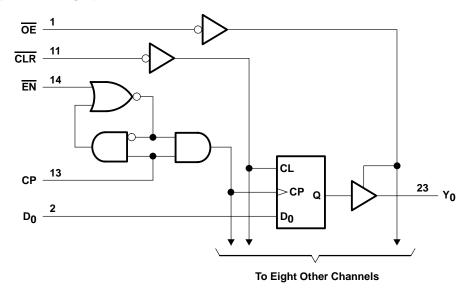
		INPUTS				RNAL PUTS	FUNCTION	
OE	CLR	EN	D	СР	Q	Y		
Н	Н	L	L	1	L	Z	Z	
Н	Н	L	Н	1	Н	Z		
Н	L	Х	Х	Х	L	Z	Clear	
L	L	Χ	Χ	X	L	L	Clear	
Н	Н	Н	Х	Х	NC	Z	Hold	
L	Н	Н	Χ	X	NC	NC	Hold	
Н	Н	L	L	1	L	Z		
Н	Н	L	Н	\uparrow	Н	Z	Load	
L	Н	L	L	\uparrow	L	L	Load	
L	Н	L	Н	1	Н	Н		

H = High logic level, L = Low logic level, X = Don't care, NC = No change,



 $[\]uparrow$ = Low-to-high transition, Z = High-impedance state

logic diagram (positive logic)



absolute maximum rating over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ_{JA} (see Note 1): P package	67°C/W
(see Note 2): Q package	61°C/W
(see Note 2): SO package	46°C/W
Ambient temperature range with power applied, T _A	. −65°C to 135°C
Storage temperature range, T _{stg}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The package thermal impedance is calculated in accordance with JESD 51-3.
 - 2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 3)

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ІОН	High-level output current			-32	mA
lOL	Low-level output current			64	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION	S	MIN	TYP [†]	MAX	UNIT
VIK	$V_{CC} = 4.75 \text{ V},$	I _{IN} = -18 mA			-0.7	-1.2	V
\/a	\/a a 4.75.\/	I _{OH} = -32 mA		2			V
VOH	V _{CC} = 4.75 V	I _{OH} = -15 mA		2.4	3.3		V
VOL	V _{CC} = 4.75 V,	I _{OL} = 64 mA			0.3	0.55	V
V _{hys}	All inputs				0.2		V
Ι _Ι	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = V_{CC}$				5	μΑ
lіН	V _{CC} = 5.25 V,	$V_{IN} = 2.7 \text{ V}$				±1	μΑ
Ι _{ΙL}	V _{CC} = 5.25 V,	V _{IN} = 0.5 V				±1	μΑ
lozh	V _{CC} = 5.25 V,	V _{OUT} = 2.7 V				10	μΑ
lozL	V _{CC} = 5.25 V,	V _{OUT} = 0.5 V				-10	μΑ
los [‡]	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 0 V		-60	-120	-225	mA
l _{off}	$V_{CC} = 0 V$,	V _{OUT} = 4.5 V				±1	μΑ
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
ΔlCC	V _{CC} = 5.25 V, V _{IN} =	3.4 V§, f ₁ = 0, Outputs or	oen		0.5	2	mA
ICCD¶	$\frac{V_{CC}}{OE} = \frac{5.25}{EN} $	it switching at 50% duty of $1 \le 0.2 \text{ V}$ or $1 \le 0.2 \text{ V}$ or $1 \le 0.2 \text{ V}$	cycle, Outputs open, 0.2 V		0.06	0.12	mA/ MHz
		One bit switching at f ₁ = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	
#	$V_{CC} = 5.25 \text{ V},$	at 50% duty cycle	V _{IN} = 3.4 V or GND		1.2	3.4	A
IC#	Outputs open, OE = EN = GND	Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2	mA
		at 50% duty cycle	V _{IN} = 3.4 V or GND		3.9	12.2	
Ci		-	-		5	10	pF
Co					9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

IC = Total supply current

I_{CC} = Power-supply current with CMOS input levels

ΔICC = Power-supply current for a TTL high input (V_{IN} = 3.4 V)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f₀ = Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

N₁ = Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the ICC formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

 $[\]$ Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

This parameter is derived for use in total power-supply calculations.

[#] IC = ICC + \triangle ICC \times DH \times NT + ICCD (f₀/2 + f₁ \times N₁) Where:

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

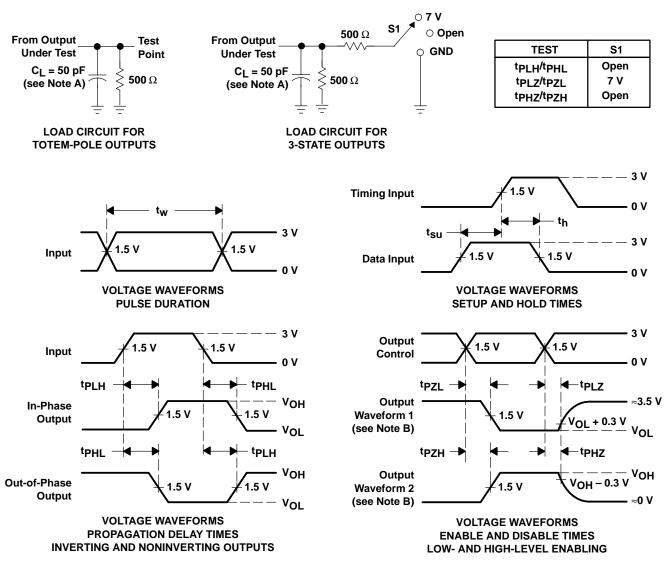
	PARAMETER		TEST LOAD	CY74FC1	CY74FCT823AT		823BT	CY74FCT823CT		UNIT
	PARAMETER	•	TEST LOAD	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t Dulas duration		CP	C _L = 50 pF,	7		6		6		ns
t _W Pulse duration	CLR low	$R_L = 500 \Omega$	6		6		6		115	
t Octor Cos before ODA	Data	C _L = 50 pF,	4		3		3		ns	
t _{su}	Setup time, before CP↑	EN	$R_L = 500 \Omega$	4		3		3		115
Ţ.,	Hold time ofter CD↑	Data	C _L = 50 pF,	2		1.5		1.5		20
l 'h	t _h Hold time, after CP↑	EN	$R_L = 500 \Omega$	2		0		0		ns
t _{rec}	Recovery time	CLR before CP↑	$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	6		6		6		ns

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	TEST LOAD	CY74FC	Г823AT	CY74FCT823B	T CY74FC	T823CT	UNIT
PARAMETER	(INPUT)	(OUTPUT)	TEST LOAD	MIN	MAX	MIN MA	X MIN	MAX	UNII
t _{PLH}	СР	Y	C _L = 50 pF,		10	7	5	6	ns
t _{PHL}	OI .	•	$R_L = 500 \Omega$		10	7	5	6	113
^t PLH	СР	Y	$C_L = 300 \text{ pF},$		20	1	5	12.5	ns
t _{PHL}	GF .		$R_L = 500 \Omega$		20	1	5	12.5	115
^t PLH	CLR	Υ	$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$		14		9	8	ns
^t PZH	ŌE	Υ	$C_L = 50 \text{ pF},$		12		8	7	
tPZL	OE	ī	$R_L = 500 \Omega$		12		8	7	ns
^t PZH	ŌE	Υ	C _L = 300 pF,		23	1	5	12.5	ns
tpzL	OL	ī	$R_L = 500 \Omega$	23 15		5	12.5		
^t PHZ	ŌE	Υ	C _L = 5 pF,		7	6	5	6	
tpLZ)E	ſ	$R_L = 500 \Omega$		7	6	5	6	ns
^t PHZ	ŌE	Y	C _L = 50 pF,		8	7	5	6.5	ns
tPLZ	5	ſ	$R_L = 500 \Omega$		8	7	5	6.5	115



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms







21-May-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CY74FCT823ATPC	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT823ATPCE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT823ATQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT823ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT823ATSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823ATSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823ATSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823ATSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823ATSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823ATSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823BTPC	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT823BTPCE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT823CTQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT823CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT823CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT823CTSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823CTSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823CTSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823CTSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823CTSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT823CTSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs. **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

21-May-2007

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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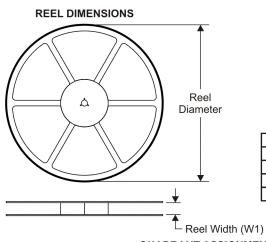
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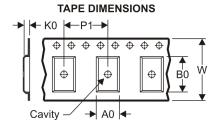




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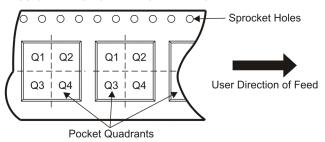
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

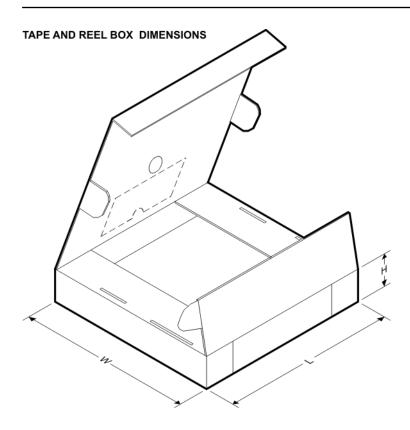
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT823ATQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT823ATSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CY74FCT823CTQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT823CTSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1



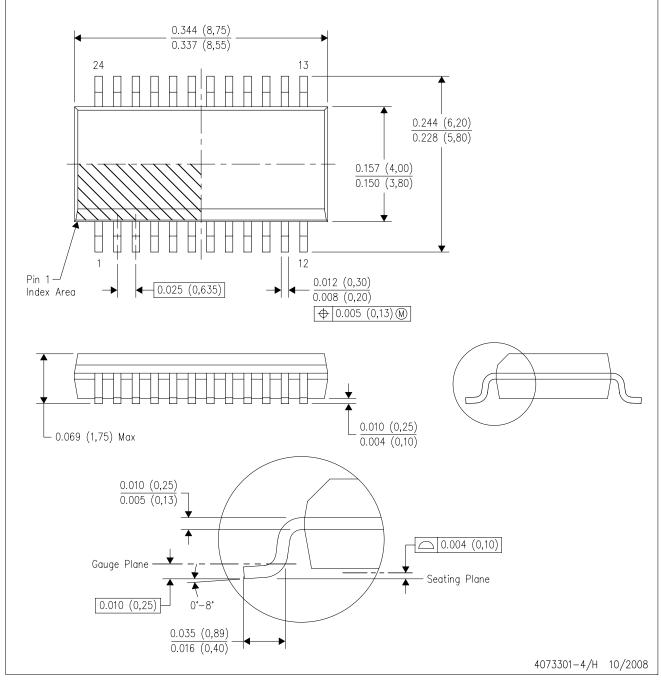


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT823ATQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
CY74FCT823ATSOCT	SOIC	DW	24	2000	346.0	346.0	41.0
CY74FCT823CTQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
CY74FCT823CTSOCT	SOIC	DW	24	2000	346.0	346.0	41.0

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE

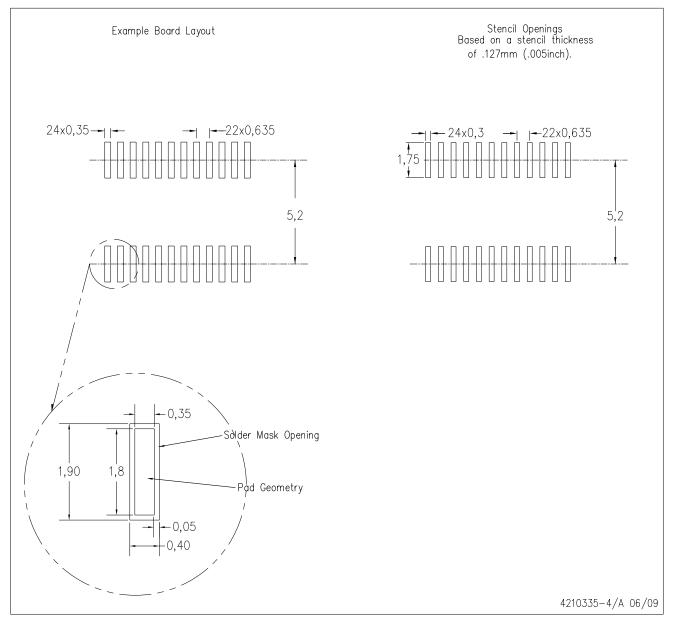


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AE.



DBQ (R-PDSO-G24)



NOTES:

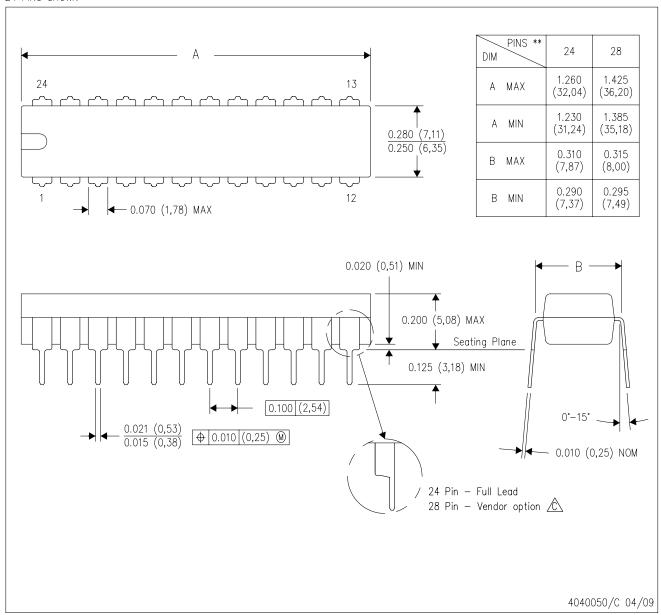
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



NT (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

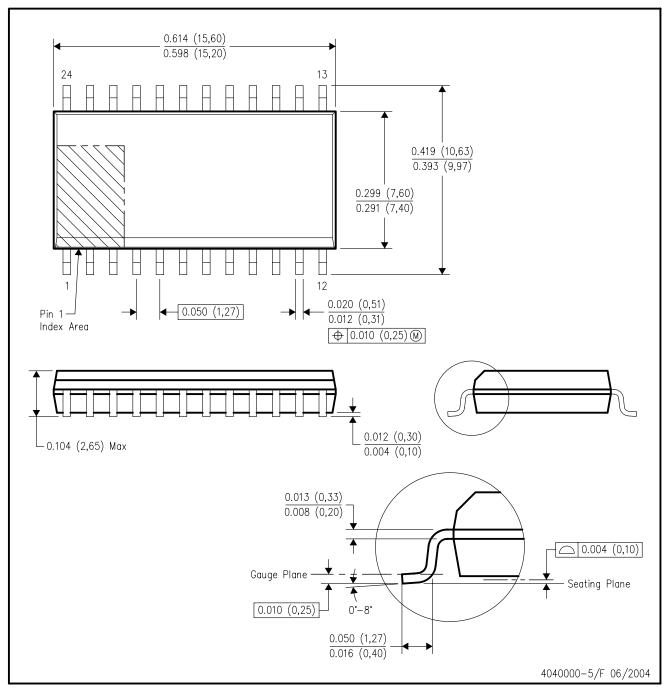
B. This drawing is subject to change without notice.

The 28 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



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